# NSN 5961-00-754-9790

Transistor - Page 1 of 1



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Inclosure Material:

Metal

**Overall Length:** 

0.375 inches

### **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

#### Features Provided:

Hermetically sealed case

### Semiconductor Material:

Germanium

### Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open

#### **Current Rating Per Characteristic:**

3.00 amperes source cutoff current

## Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

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